

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:  
SALZER, WILLIAM E. et al

§ Patent No.: 6895596 B1

Application No.: 08/997622

§ Issue Date: 5/17/2005

Filed: 12-23-1997

§ Examiner: Vivek Srivastava

§ Group Art Unit: 2611

§ Docket No.: SC10321C

Title: CIRCUIT AND METHOD FOR INTERLEAVING A DATA STREAM

Certificate of Submission

I hereby certify that this correspondence is being submitted to the USPTO, Alexandria, VA.

Addressed per C.F.R. § 1.1(a) and deposited with the United States Postal Service with sufficient postage as first class mail.

Facsimile transmitted in accordance with C.F.R. §1.6(d).

Submitted electronically via EFS in accordance with "Legal Framework for EFS Web".

*March 20, 2008*

Date of Submission

*Teresa Shephard*

Signature

*Teresa Shephard*

Printed Name of Person Signing Certificate

Commissioner for Patents  
Alexandria, VA 22313

SUBMISSION OF CERTIFICATE OF CORRECTION

Dear Commissioner:

Enclosed is a Certificate of Correction listing error(s) in the subject patent. Please enter these corrections. Since at least some of the errors appear to be on the part of the Applicant, the required fee may be charged to Deposit Account 503079 via the Electronic Filing System.

Respectfully submitted,

*3/18/08*  
Date

*Susan C. Hill*

HILL, SUSAN C.  
Attorney for Applicant(s)  
Registration No. 35896  
Telephone No. (512) 996-6839  
Facsimile No. (512) 996-6854

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CERTIFICATE OF CORRECTION**

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PATENT NO.: 6895596 B1  
APPLICATION NO: 08/997622  
DATE: 12-23-1997  
FIRST NAMED INVENTOR: SALZER, WILLIAM E.

It is certified that error appears in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

In Column 4, Line 46, Claim No. 1:

Change "second memory circuits for selecting between the fit" to--second memory circuits for selecting between the first--

In Column 4, Line 63, Claim No. 5:

Change "amount of data stored in tile first memory circuit" to--amount of data stored in the first memory circuit--

In Column 5, Line 10, Claim No. 8:

Change "storing the data stream including storing data of the fast" to--storing the data stream including storing data of the first--

MAILING ADDRESS OF SENDER (Please do not use customer number below)

Freescale Semiconductor, Inc.  
Law Department  
7700 West Parmer Lane PL02  
Austin, TX 78729